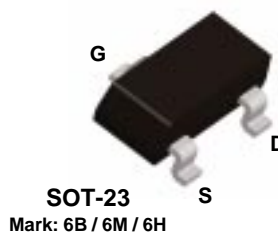
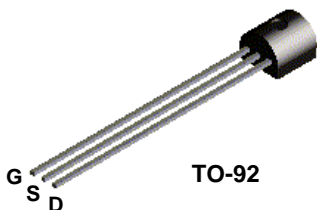


**2N5484
2N5485
2N5486**

**MMBF5484
MMBF5485
MMBF5486**



N-Channel RF Amplifier

This device is designed primarily for electronic switching applications such as low On Resistance analog switching. Sourced from Process 50.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{DG}	Drain-Gate Voltage	25	V
V _{GS}	Gate-Source Voltage	- 25	V
I _{GF}	Forward Gate Current	10	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
		2N5484	*MMBF5484	
P _D	Total Device Dissipation	350	225	mW
	Derate above 25°C	2.8	1.8	mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	125		°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	357	556	°C/W

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

2N5484 / 2N5485 / 2N5486 / MMBF5484 / MMBF5485 / MMBF5486

N-Channel RF Amplifier

(continued)

Electrical Characteristics

TA = 25°C unless otherwise noted

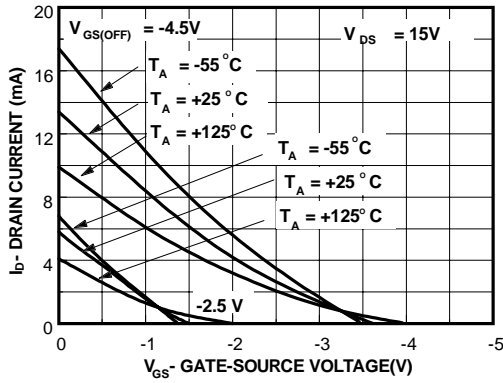
Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	$I_G = -1.0 \mu A, V_{DS} = 0$	-25			V
I_{GSS}	Gate Reverse Current	$V_{GS} = -20 V, V_{DS} = 0$ $V_{GS} = -20 V, V_{DS} = 0, T_A = 100^\circ C$			-1.0 -0.2	nA μA
$V_{GS(off)}$	Gate-Source Cutoff Voltage	$V_{DS} = 15 V, I_D = 10 nA$	-0.3 -0.5 -2.0		-3.0 -4.0 -6.0	V V V
ON CHARACTERISTICS						
I_{DSS}	Zero-Gate Voltage Drain Current*	$V_{DS} = 15 V, V_{GS} = 0$	1.0 4.0 8.0		5.0 10 20	mA mA mA
SMALL SIGNAL CHARACTERISTICS						
g_{fs}	Forward Transfer Conductance	$V_{DS} = 15 V, V_{GS} = 0, f = 1.0 kHz$	3000 3500 4000		6000 7000 8000	$\mu mhos$ $\mu mhos$ $\mu mhos$
$Re(y_{is})$	Input Conductance	$V_{DS} = 15 V, V_{GS} = 0, f = 100 MHz$ $V_{DS} = 15 V, V_{GS} = 0, f = 400 MHz$			100 1000	$\mu mhos$ $\mu mhos$
g_{os}	Output Conductance	$V_{DS} = 15 V, V_{GS} = 0, f = 1.0 kHz$			50 60 75	$\mu mhos$ $\mu mhos$ $\mu mhos$
$Re(y_{os})$	Output Conductance	$V_{DS} = 15 V, V_{GS} = 0, f = 100 MHz$ $V_{DS} = 15 V, V_{GS} = 0, f = 400 MHz$			75 100	$\mu mhos$ $\mu mhos$
$Re(y_{fs})$	Forward Transconductance	$V_{DS} = 15 V, V_{GS} = 0, f = 100 MHz$ $V_{DS} = 15 V, V_{GS} = 0, f = 400 MHz$	2500 3000 3500			$\mu mhos$ $\mu mhos$ $\mu mhos$
C_{iss}	Input Capacitance	$V_{DS} = 15 V, V_{GS} = 0, f = 1.0 MHz$			5.0	pF
C_{riss}	Reverse Transfer Capacitance	$V_{DS} = 15 V, V_{GS} = 0, f = 1.0 MHz$			1.0	pF
C_{oss}	Output Capacitance	$V_{DS} = 15 V, V_{GS} = 0, f = 1.0 MHz$			2.0	pF
NF	Noise Figure	$V_{DS} = 15 V, R_G = 1.0 k\Omega, f = 100 MHz$ $V_{DS} = 15 V, R_G = 1.0 k\Omega, f = 400 MHz$ $V_{DS} = 15 V, R_G = 1.0 k\Omega, f = 100 MHz$ $V_{DS} = 15 V, R_G = 1.0 k\Omega, f = 400 MHz$		4.0	3.0 2.0 4.0	dB dB dB dB

*Pulse Test: Pulse Width $\leq 300 ms$, Duty Cycle $\leq 2\%$

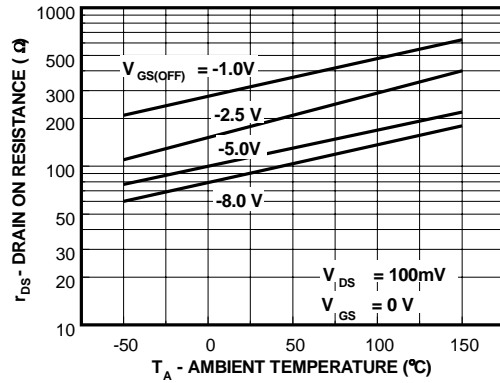
2N5484 / 2N5485 / 2N5486 / MMBF5484 / MMBF5485 / MMBF5486

Typical Characteristics

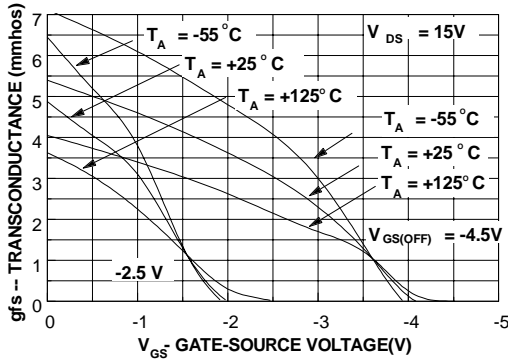
Transfer Characteristics



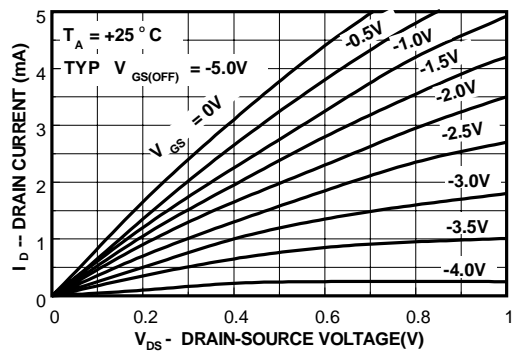
Channel Resistance vs Temperature



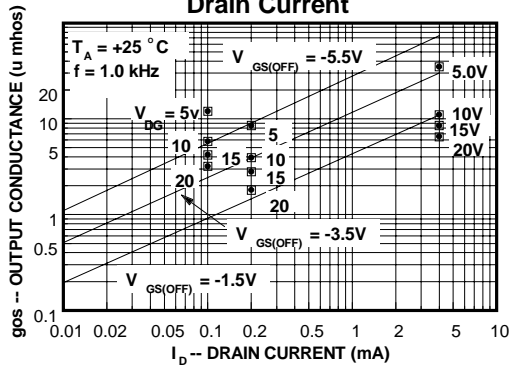
Transconductance Characteristics



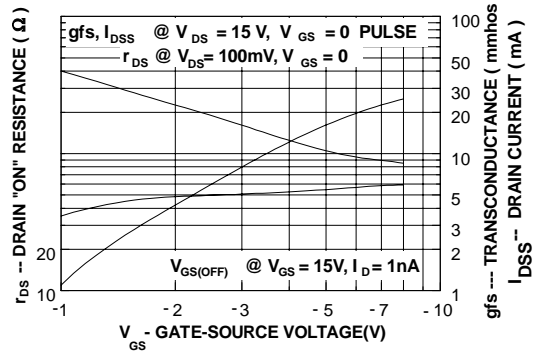
Common Drain-Source Characteristics



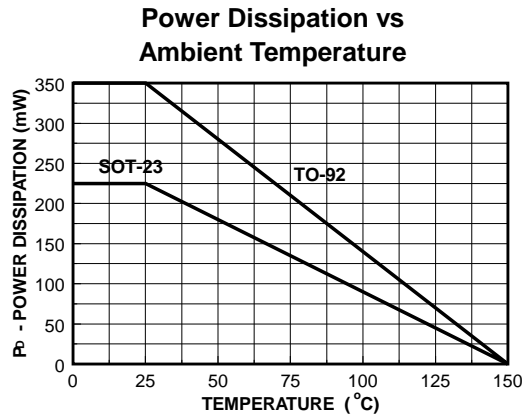
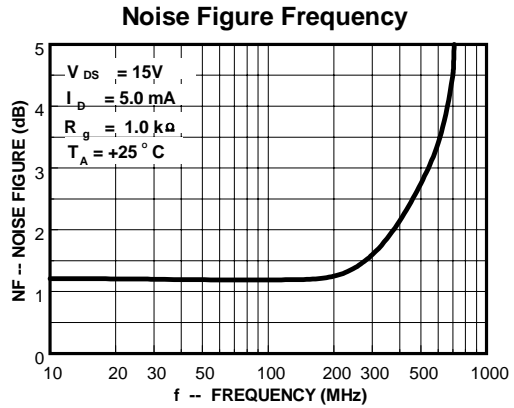
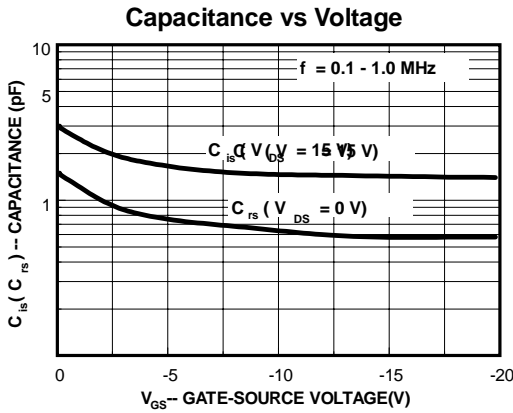
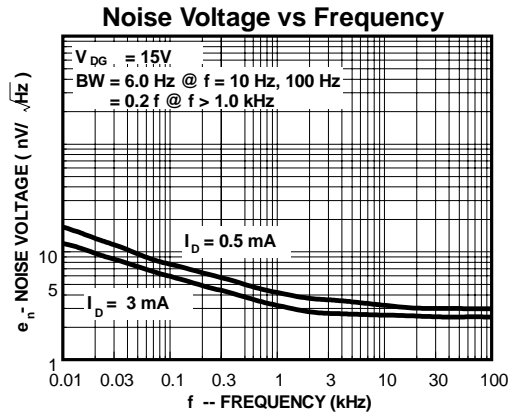
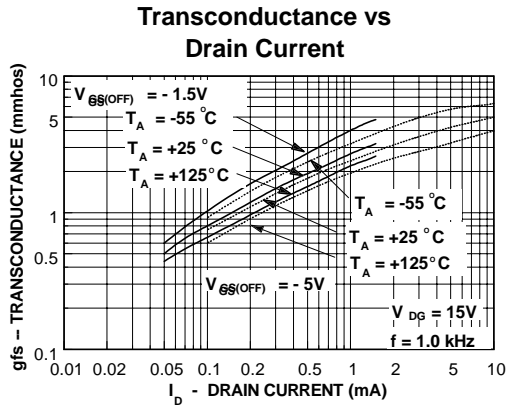
Output Conductance vs Drain Current



Transconductance Parameter Interactions

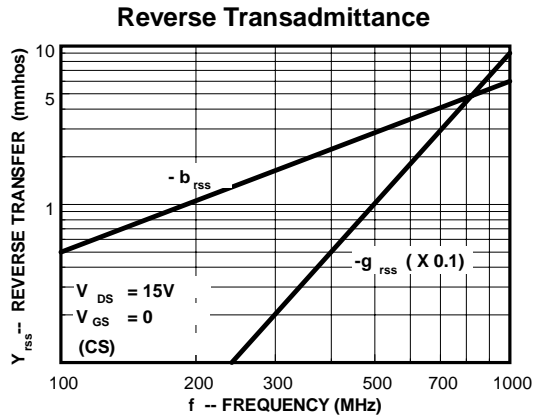
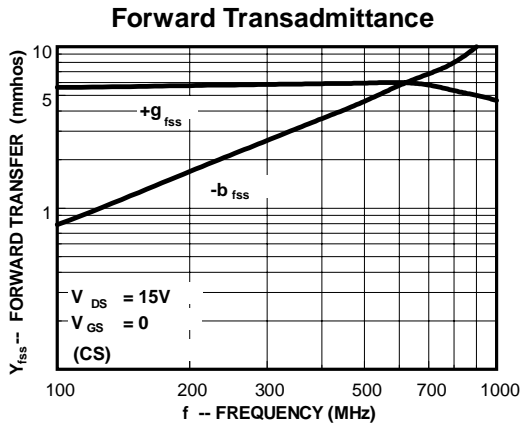
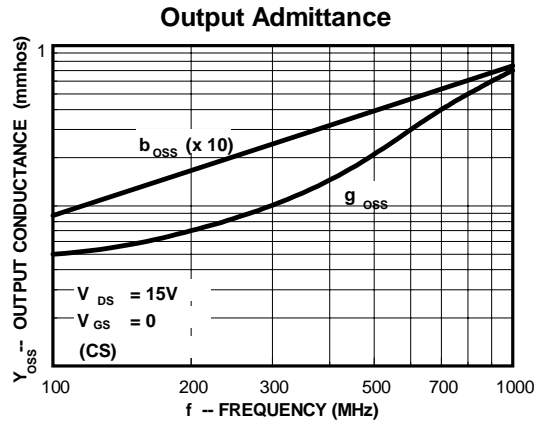
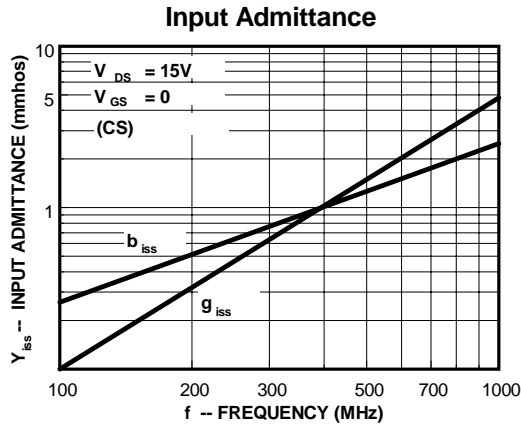


Typical Characteristics (continued)



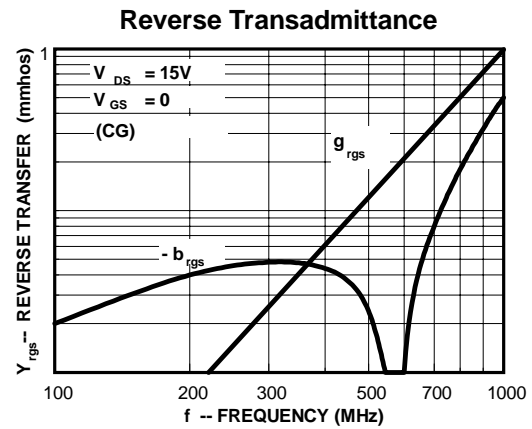
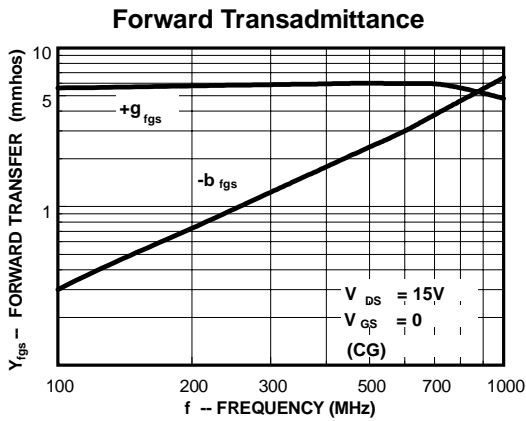
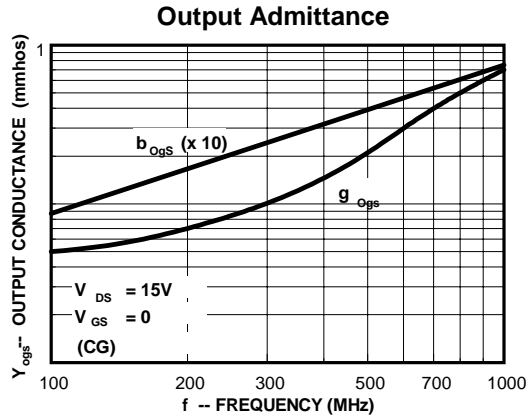
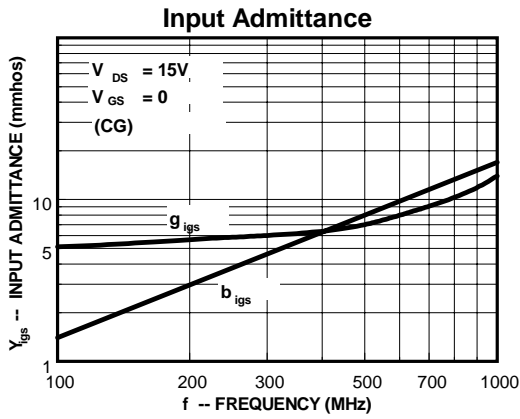
2N5484 / 2N5485 / 2N5486 / MMBF5484 / MMBF5485 / MMBF5486

Common Source Characteristics



2N5484 / 2N5485 / 2N5486 / MMBF5484 / MMBF5485 / MMBF5486

Common Gate Characteristics



TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	ISOPLANAR™
CoolFET™	MICROWIRE™
CROSSVOLT™	POP™
E ² CMOS™	PowerTrench™
FACT™	QS™
FACT Quiet Series™	Quiet Series™
FAST®	SuperSOT™-3
FASTr™	SuperSOT™-6
GTO™	SuperSOT™-8
HiSeC™	TinyLogic™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.